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Substitute for Form 1449A/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (use as many sheets as necessary)				Complete If Known	
				Application Number	
				Filing Date	07/14/2003
				First Named Inventor	Kelth E. Kunz, et al.
				Group Art Unit	
Examiner Name					
Sheet	1	of	1	Attorney Docket No.	TI-33676.1

U.S. PATENT DOCUMENTS						
Exam. Initials*	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code <sup>2</sup> (if known)			
<i>AK</i>	AA	4,692,781		Rountree et al.	09/08/1987	
<i>AK</i>	AB	4,855,620		Duvvury et al.	08/08/1989	
<i>AK</i>	AC	5,012,317		Rountree	04/30/1991	
<i>AK</i>	AD	5,907,462		Chatterjee et al.	05/25/1999	
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	AF					
	AG					
	AH					
	AI					
	AJ					

FOREIGN PATENT DOCUMENTS								
Exam. Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Name of Patentee or Applicant of Cited Doc.	Date of Pub. of Cited Doc. (mm-dd-yyyy)	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>2</sup> (if known)				
	BA							
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS					T <sup>2</sup>
Exam. Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			
	CA	Rountree et al., "A Process-Tolerant Input Protection Circuit for Advanced CMOS Processes," 1988 EOS/ESD Symposium, pp. 201-05			
	CB	Duvvury et al., "Substrate Pump NMOS for ESD Protection Applications," 2000 EOS/ESD Symposium, Paper 1A.2.1, pp. 7-17			
	CC	Kunz et al., "5-V Tolerant Fail-safe ESD Solutions for 0.18 um Logic CMOS Process," 2001 ESD/EOS Symposium, September 11, 2001			
	CD				
	CE				
	CF				
	CG				
	CH				
	CI				
	CJ				

Examiner Signature	<i>As Jackson</i>	Date Considered	6-10-04
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup>Unique citation designation number. <sup>2</sup>Applicant is to place a check mark here if English Translation is attached.